

Mid-Power LED - 3030E Series

**STW8C12E-E200C0IZP**

S1W0-3030xx8003-00000000-00013



## Product Brief

### Description

- This White Colored surface-mount LED comes in standard package dimension.
- Package Size : 3.3x3.0x0.75mm
- It has a substrate made up of a molded plastic reflector sitting on top of a lead frame.
- The die is attached within the reflector cavity and the cavity is encapsulated by silicone.
- The package design coupled with careful selection of component materials allow these products to perform with high reliability.

### Features and Benefits

- Thermally Enhanced Package Design
- High Color Quality with CRI Min.80
- RoHS compliant
- Pb-free Reflow Soldering Application
- Hot binning(60degree standard) product

### Key Applications

- Interior lighting
- General lighting
- Indoor displays
- Architectural / Decorative lighting

**Table 1. Product Selection Table**

Part Number	Color	Nominal CCT	Order Code	CRI
				Min
STW8C12E-E200C0IZP	Cool White	6500K	S1W0-3030658003-00000000-00013	80
		5700K	S1W0-3030578003-00000000-00013	
		5000K	S1W0-3030508003-00000000-00013	
	Neutral White	4000K	S1W0-3030408003-00000000-00013	
		3500K	S1W0-3030358003-00000000-00013	
	Warm White	3000K	S1W0-3030308003-00000000-00013	
		2700K	S1W0-3030278003-00000000-00013	

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## Performance Characteristics

**Table 2.1 Product Selection Guide,  $I_F = 65\text{mA}$ ,  $T_J = 25^\circ\text{C}$ , RH30%**

Part Number	Nominal	Type. VF	Typ. Luminous	Typ. Luminous
	CCT [K] <sup>[1]</sup>	[V]	Flux $\Phi_V$ <sup>[2]</sup> [lm]	Efficacy [lm/W]
S1W0-3030658003-00000000-00013	6500	2.68	41.3	237.1
S1W0-3030578003-00000000-00013	5700	2.68	42.1	241.8
S1W0-3030508003-00000000-00013	5000	2.68	42.7	245.3
S1W0-3030408003-00000000-00013	4000	2.68	43.1	247.7
S1W0-3030358003-00000000-00013	3500	2.68	42.3	243.0
S1W0-3030308003-00000000-00013	3000	2.68	41.5	238.3
S1W0-3030278003-00000000-00013	2700	2.68	40.6	233.0

**Table 2.2 Product Selection Guide,  $I_F = 65\text{mA}$ ,  $T_J = 60^\circ\text{C}$ , RH30%**

Part Number	Nominal	Type. VF	Typ. Luminous	Typ. Luminous
	CCT [K] <sup>[1]</sup>	[V]	Flux $\Phi_V$ <sup>[2]</sup> [lm]	Efficacy [lm/W]
S1W0-3030658003-00000000-00013	6500	2.65	39.8	230.9
S1W0-3030578003-00000000-00013	5700	2.65	40.6	235.7
S1W0-3030508003-00000000-00013	5000	2.65	41.1	238.6
S1W0-3030408003-00000000-00013	4000	2.65	41.5	241.0
S1W0-3030358003-00000000-00013	3500	2.65	40.8	236.9
S1W0-3030308003-00000000-00013	3000	2.65	40.0	232.1
S1W0-3030278003-00000000-00013	2700	2.65	39.0	226.2

**Notes :**

- (1) Correlated Color Temperature is derived from the CIE 1931 Chromaticity diagram.
- (2) Seoul Semiconductor maintains a tolerance of  $\pm 5\%$  on Flux and power measurements.

The luminous Flux was measured at the peak of the spatial pattern which may not be aligned with the mechanical axis of the LED package.

## Performance Characteristics

**Table 3. Characteristics,  $I_F=65\text{mA}$ ,  $T_J=60^\circ\text{C}$ , RH30%**

Parameter	Symbol	Value			Unit
		Min.	Typ.	Max.	
Forward Current	$I_F$	5	65	-	mA
Forward Voltage	$V_F$	2.6	2.65	2.8	V
CRI <sup>[3]</sup>	$R_a$	80	-	90	
Luminous Flux <sup>[1]</sup> (4000K) <sup>[2]</sup>	Flux	-	41.5	-	lm
Viewing Angle	$2\theta_{1/2}$	-	120	-	Deg.
Thermal resistance (J to S) <sup>[4]</sup>	$R\theta_{J-S}$	-	7.5		$^\circ\text{C/W}$
Turn-on voltage	$V_F(1\mu\text{A})$	1.9	-	2.7	V
ESD Sensitivity(HBM)	-	Class 3A JEDEC JS-001-2017			

**Table 4. Absolute Maximum Ratings**

Parameter	Symbol	Value	Unit
Forward Current	$I_F$	200	mA
Power Dissipation	$P_D$	0.6	W
Junction Temperature <sup>[5]</sup>	$T_j$	125	$^\circ\text{C}$
Operating Temperature	$T_{opr}$	-40 ~ + 85	$^\circ\text{C}$
Storage Temperature	$T_{stg}$	-40 ~ + 100	$^\circ\text{C}$

### Notes :

(1) Seoul Semiconductor maintains a tolerance of  $\pm 5\%$  on Flux and power measurements.

(2) Correlated Color Temperature is derived from the CIE 1931 Chromaticity diagram.

Color coordinate :  $\pm 0.005$ , CCT  $\pm 5\%$  tolerance,  $\pm 0.1$  on VF measurements

(3) Test data at  $60^\circ\text{C}$  with CRI, Tolerance is  $\pm 2.0$  on CRI

(4) Thermal resistance is junction to Solder.

(5) The products are sensitive to static electricity and must be carefully taken when handling products

(6) It is recommended minimum current 5mA in order to avoid unstable brightness, and may vary depending on circuit configuration

(7) It is recommended to use it in the condition that the reliability is secured within the Max value.

- Calculated performance values are for reference only.
- All measurements were made under the standardized environment of Seoul Semiconductor.

# Characteristics Graph

Fig 1. Color Spectrum

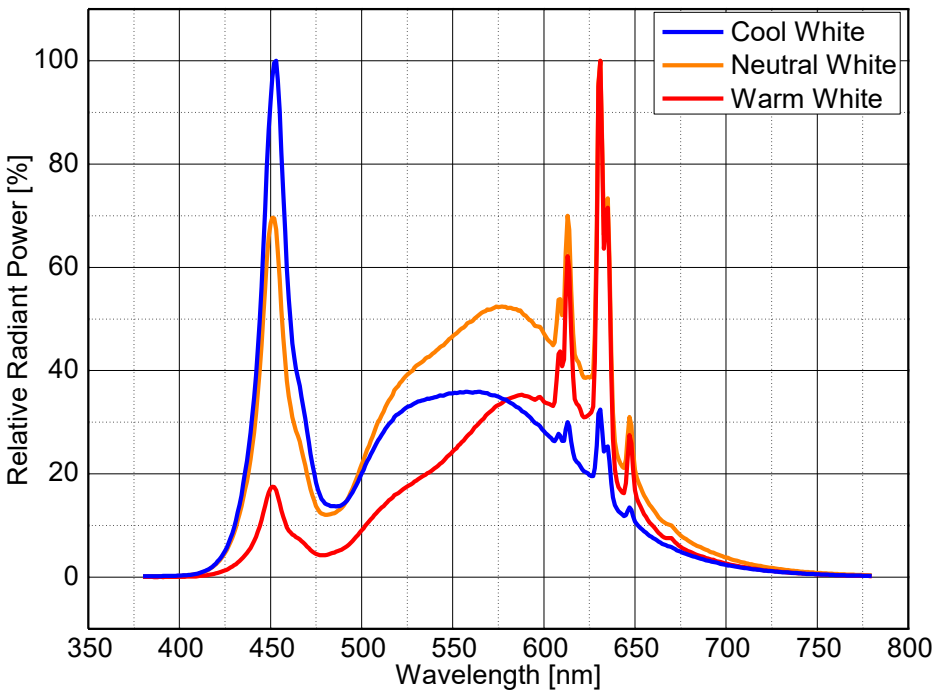
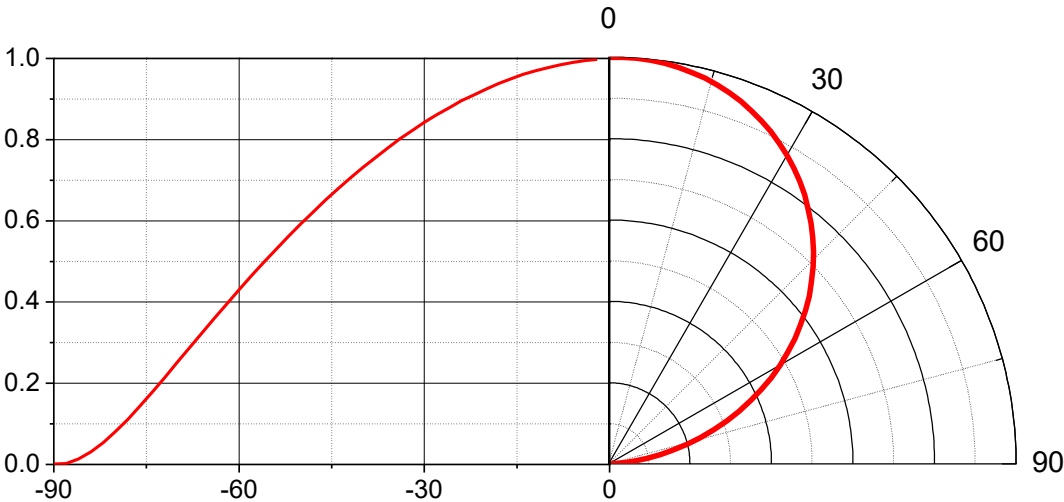
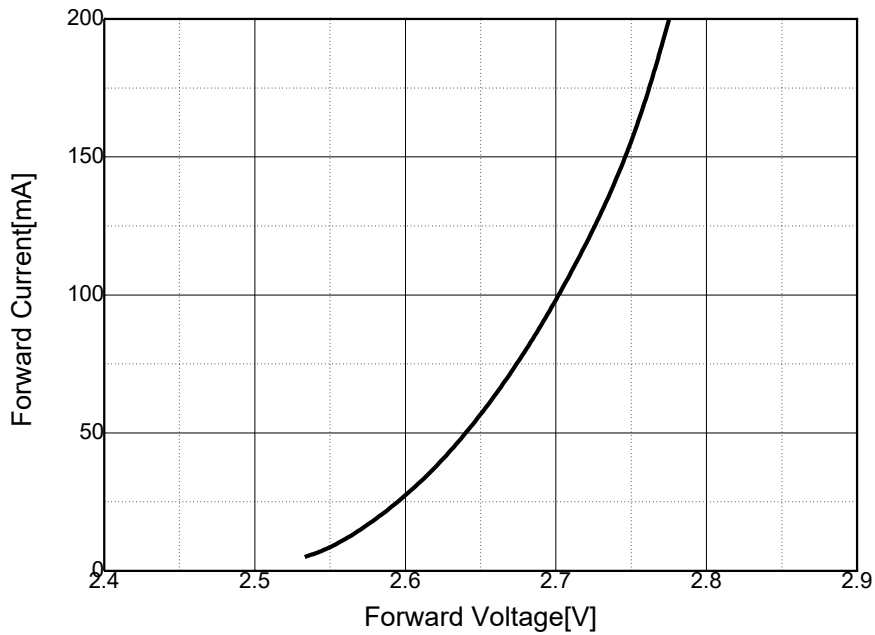


Fig 2. Radiant Pattern

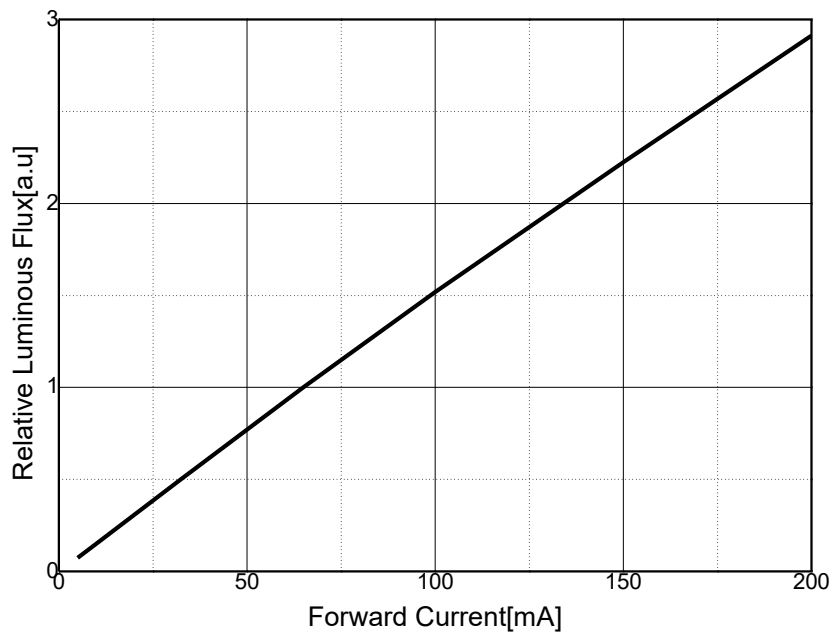


## Characteristics Graph

**Fig 3. Forward Voltage vs. Forward Current**



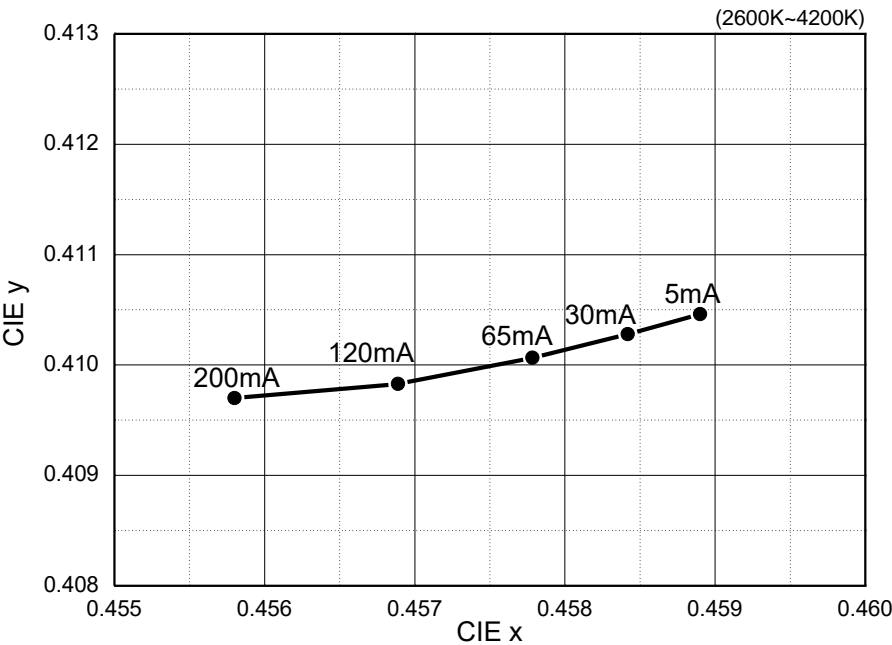
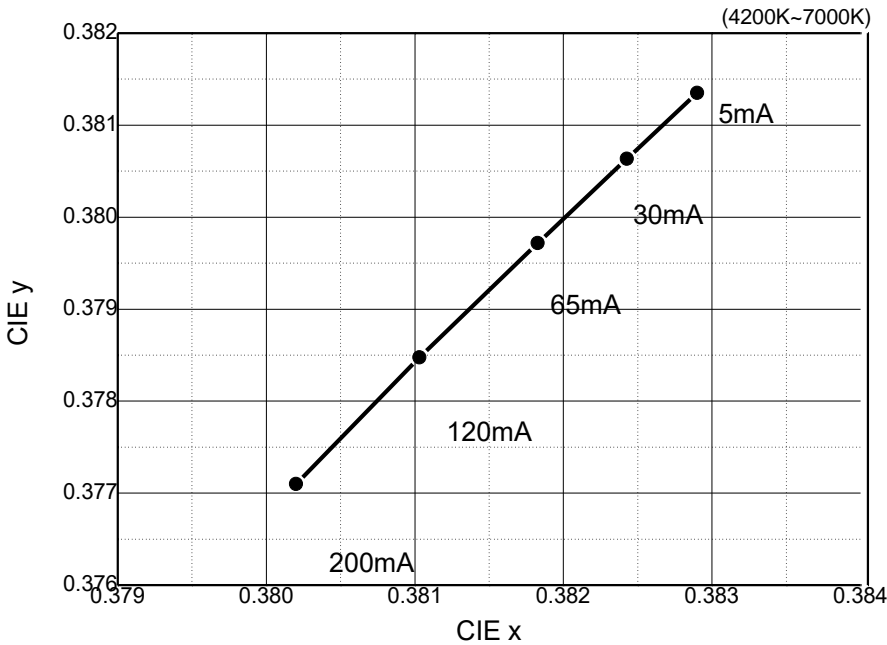
**Fig 4. Forward Current vs. Relative Luminous Flux**



- Use of less than 5mA is not recommended

# Characteristics Graph

Fig 5. Forward Current vs. CIE x, y Shift



- Use of less than 5mA is not recommended

# Characteristics Graph

Fig 6. Junction Temperature vs. Relative Luminous Flux,  $I_F=65\text{mA}$

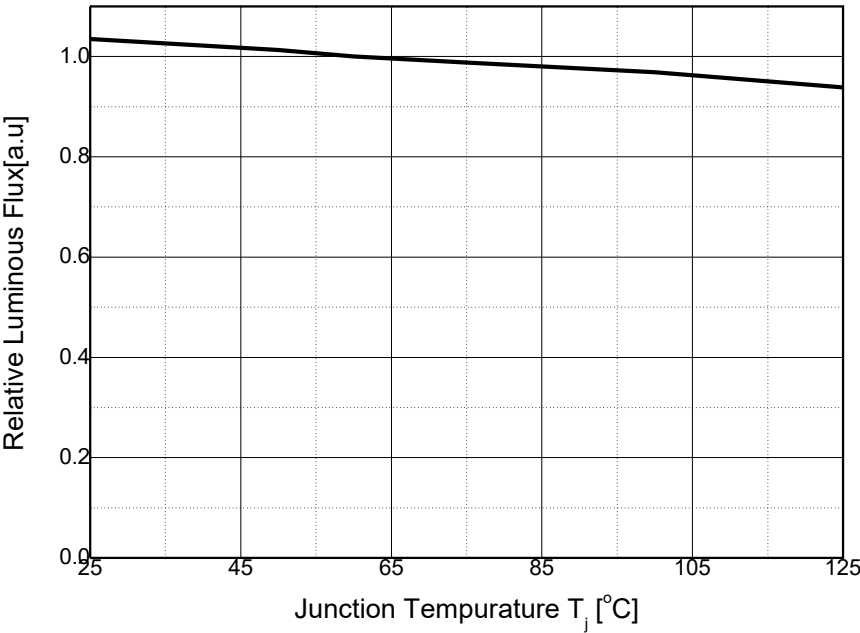
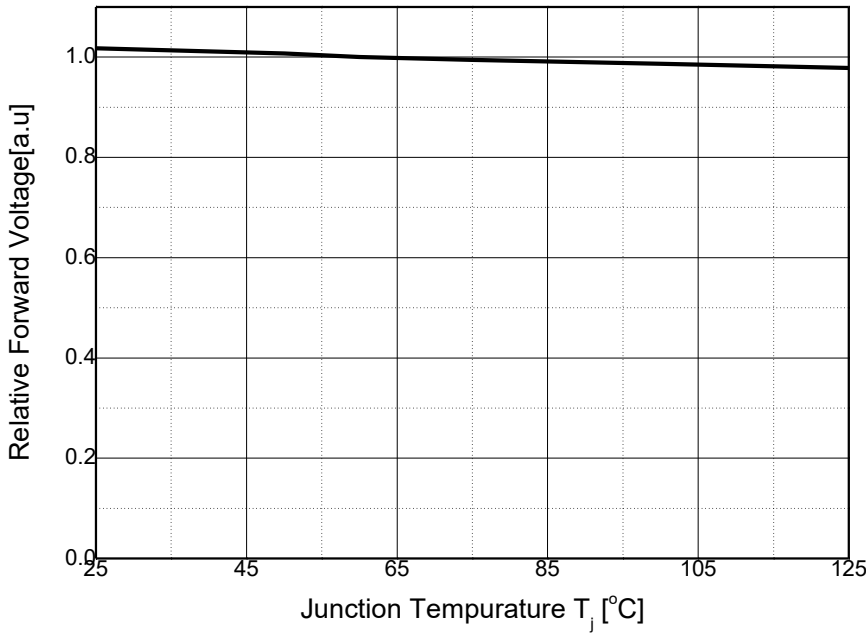


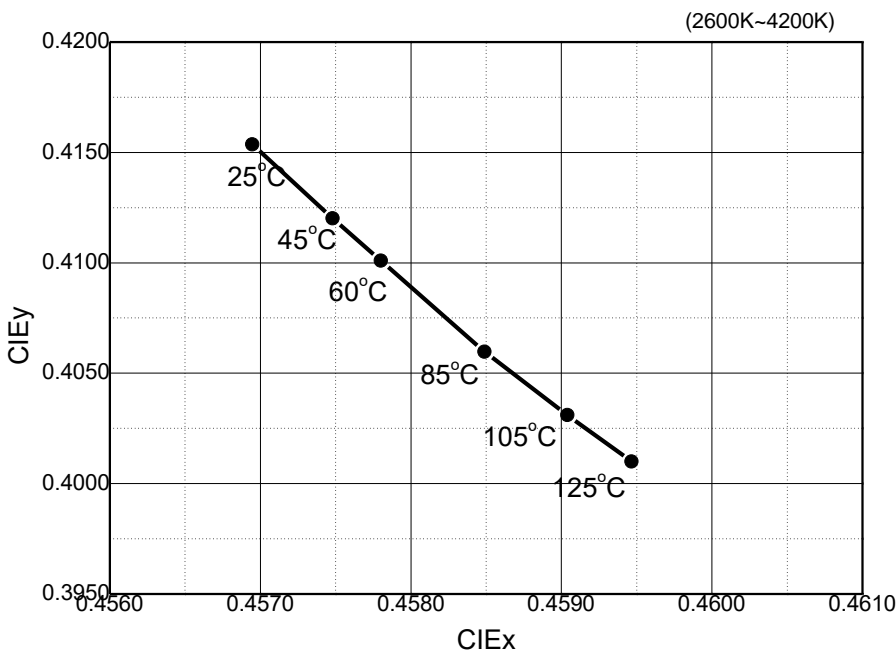
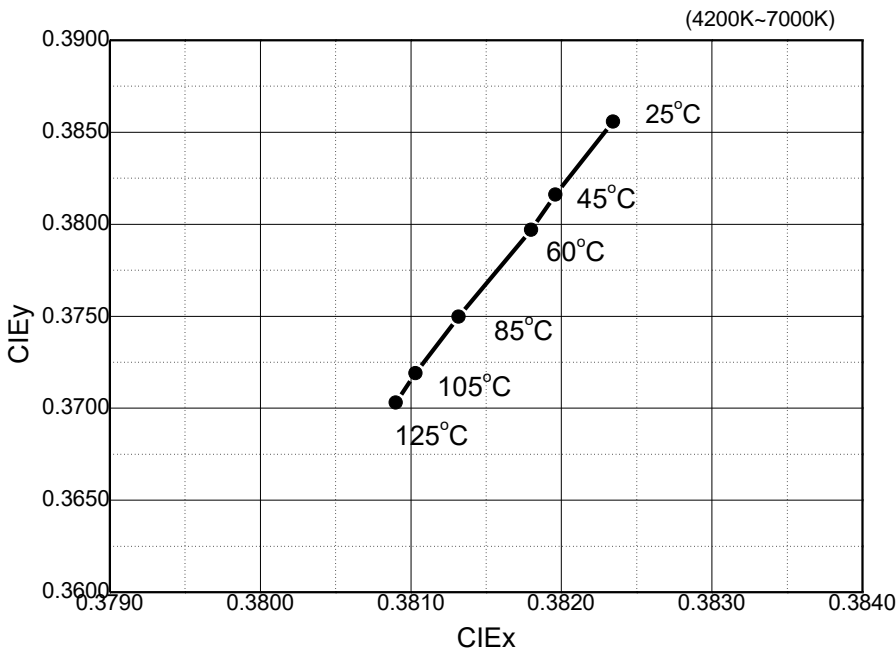
Fig 7. Junction Temperature vs. Relative Forward Voltage,  $I_F=65\text{mA}$





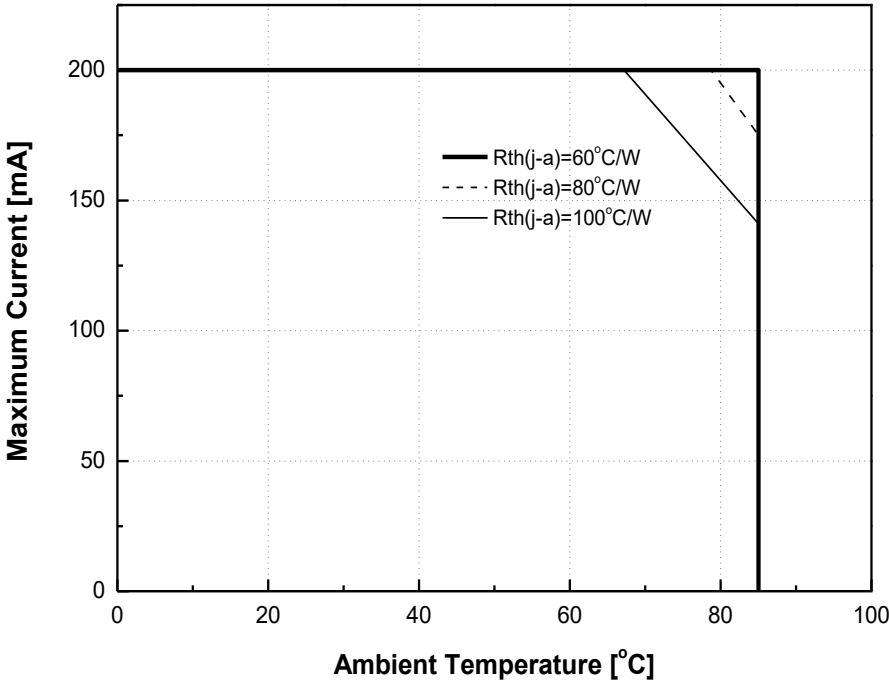
# Characteristics Graph

Fig 8. Chromaticity Coordinate vs. Junction Temperature,  $I_F=65mA$



# Characteristics Graph

Fig 9. Ambient Temperature vs. Maximum Forward Current,  $T_{j,max} = 125^{\circ}C$



## Color Bin Structure

Table 5. Bin Code description,  $T_j=60^{\circ}\text{C}$ ,  $I_F=65\text{mA}$

Part Number	Luminous Flux (lm)			Color Chromaticity Coordinate	Typical Forward Voltage (V)		
	Bin Code	Min.	Max.		Bin Code	Min.	Max.
STW8C12E-E200C0IZP	V5	37.5	39.0	Refer to page.13	Y0	2.60	2.70
	W0	39.0	40.5		Y1	2.70	2.80
	W5	40.5	42.0				
	X0	42.0	43.5				

Table 6. Flux rank distribution

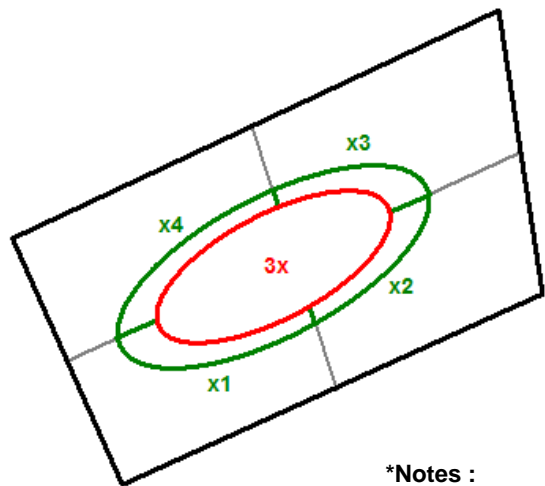
 Available ranks

CCT	CIE	Flux Rank			
6000 ~ 7000K	A	V5	W0	W5	X0
5300 ~ 6000K	B	V5	W0	W5	X0
4700 ~ 5300K	C	V5	W0	W5	X0
3700 ~ 4200K	E	V5	W0	W5	X0
3200 ~ 3700K	F	V5	W0	W5	X0
2900 ~ 3200K	G	V5	W0	W5	X0
2600 ~ 2900K	H	V5	W0	W5	X0

**\*Notes :**

- All measurements were made under the standardized environment of Seoul Semiconductor.
- In order to ensure availability, single color rank will not be orderable.

# Color Bin Structure



**\*Notes :**  
 Red color : 3step, Green color : 4step

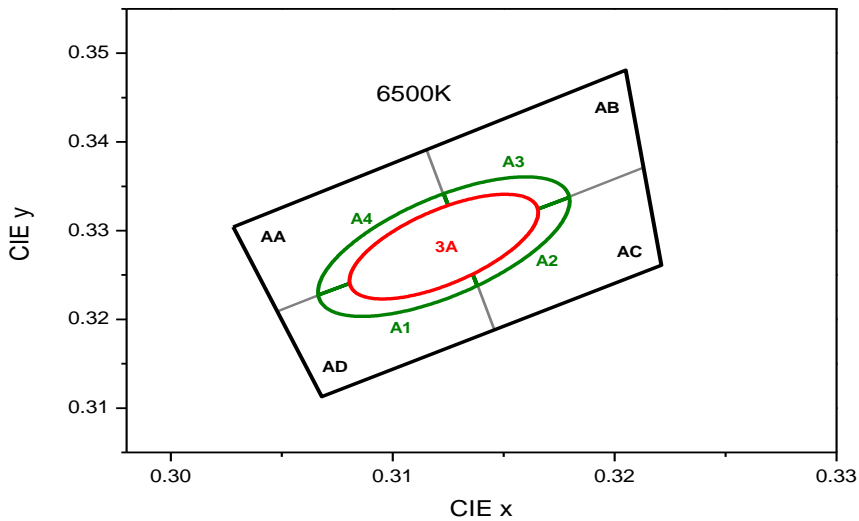
**\* Only for reference**

Item	Bin #1	Bin #2	Note
CIE	3x	3x	3step Kitting
	x1	x3	4step Kitting
	x2	x4	
VF	Do not specify rank, randomly assigned.		N/A
LM	Do not specify rank, randomly assigned.		N/A

**\*Notes :**  
 'x' can be A(6500K),B(5700K),C(5000K),D(4500K),E(4000K),F(3500K),  
 G(3000K),H(2700K),

## Color Bin Structure

CIE Chromaticity Diagram (Cool white),  $T_j=60^\circ\text{C}$ ,  $I_F=65\text{mA}$



3step(3A)				4step(4A)			
Center point		0.3123 : 0.3282		Center point		0.3123 : 0.3282	
Major Axis a		0.0067		Major Axis a		0.0089	
Minor Axis b		0.0029		Minor Axis b		0.0038	
Ellipse Rotation Angle		59		Ellipse Rotation Angle		59	

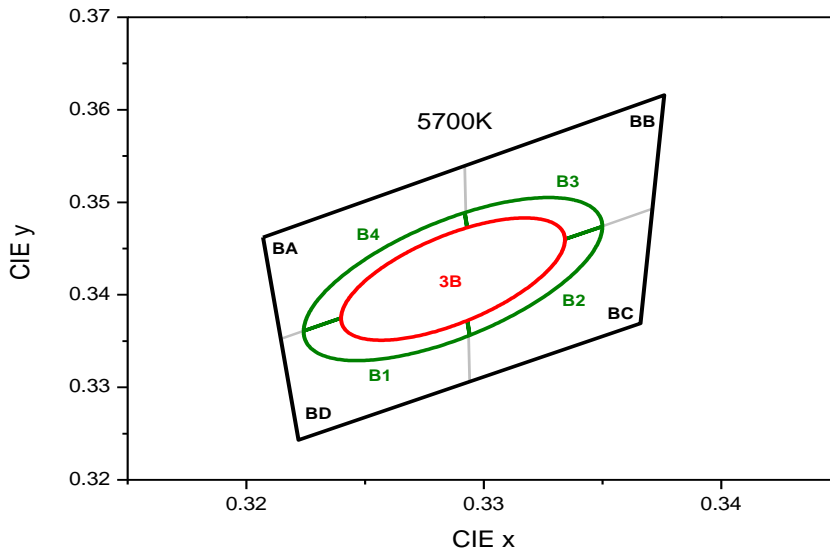
A1		A2		A3		A4	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.3066	0.3227	0.3138	0.3238	0.318	0.3338	0.3123	0.3341
0.3081	0.3241	0.3136	0.3251	0.3165	0.3324	0.3125	0.3328
0.3138	0.3238	0.3180	0.3338	0.3123	0.3341	0.3066	0.3227
0.3136	0.3251	0.3165	0.3324	0.3125	0.3328	0.3081	0.3241

AA		AB		AC		AD	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.3028	0.3304	0.3115	0.3393	0.3131	0.329	0.3048	0.3209
0.3048	0.3209	0.3131	0.3290	0.3146	0.3187	0.3068	0.3113
0.3131	0.3290	0.3213	0.3371	0.3221	0.3261	0.3146	0.3187
0.3115	0.3393	0.3205	0.3481	0.3213	0.3371	0.3131	0.3290

## Color Bin Structure

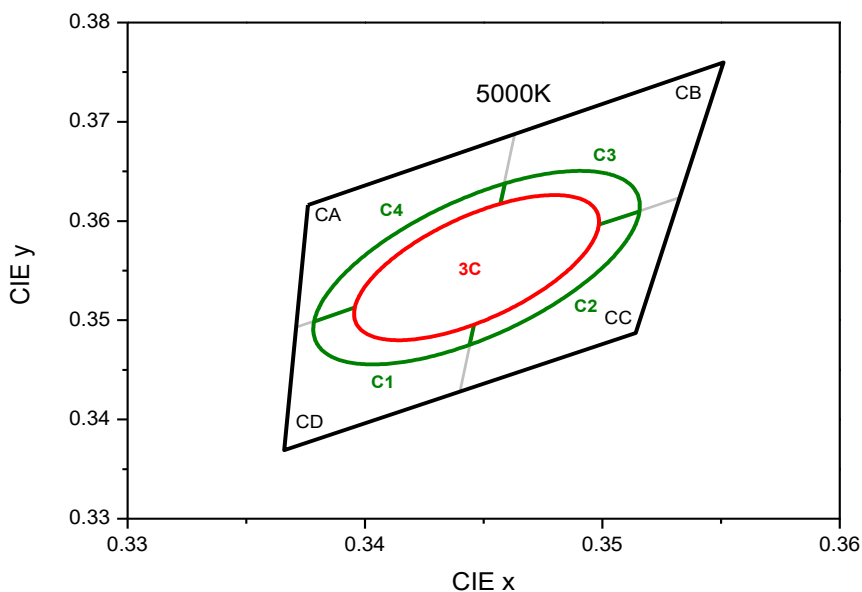
CIE Chromaticity Diagram (Cool white),  $T_j=60^{\circ}\text{C}$ ,  $I_F=65\text{mA}$



3step(3B)				4step(4B)			
Center point		0.3287 : 0.3417		Center point		0.3287 : 0.3417	
Major Axis a		0.0075		Major Axis a		0.0100	
Minor Axis b		0.0032		Minor Axis b		0.0043	
Ellipse Rotation Angle		59		Ellipse Rotation Angle		59	
B1		B2		B3		B4	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.3224	0.3361	0.3294	0.3356	0.3350	0.3474	0.3292	0.3489
0.3240	0.3375	0.3293	0.3373	0.3334	0.3460	0.3293	0.3472
0.3294	0.3356	0.3350	0.3474	0.3292	0.3489	0.3224	0.3361
0.3293	0.3373	0.3334	0.3460	0.3293	0.3472	0.3240	0.3375
BA		BB		BC		BD	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.3207	0.3462	0.3292	0.3539	0.3293	0.3423	0.3215	0.3353
0.3215	0.3353	0.3293	0.3423	0.3294	0.3306	0.3222	0.3243
0.3293	0.3423	0.3371	0.3493	0.3366	0.3369	0.3294	0.3306
0.3292	0.3539	0.3376	0.3616	0.3371	0.3493	0.3293	0.3423

## Color Bin Structure

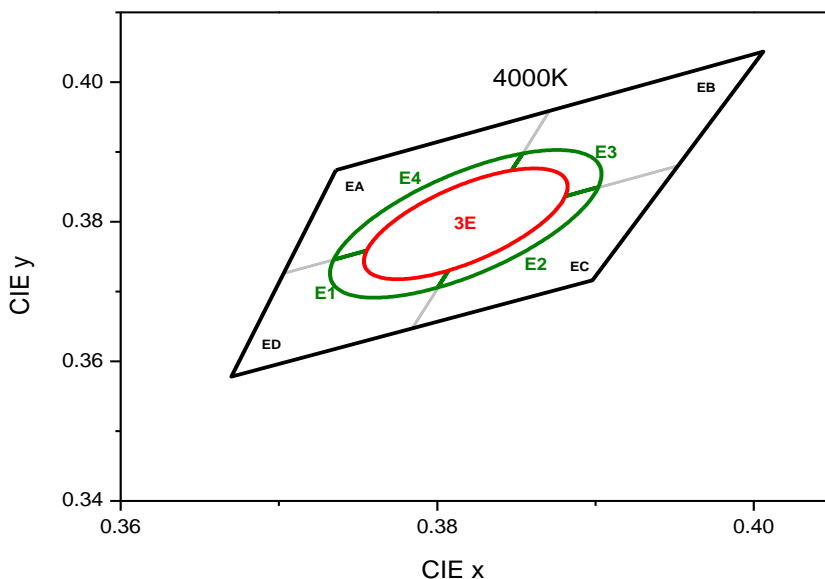
CIE Chromaticity Diagram (Cool white),  $T_j=60^\circ\text{C}$ ,  $I_F=65\text{mA}$



3step(3C)				4step(4C)			
Center point		0.3447 : 0.3553		Center point		0.3447 : 0.3553	
Major Axis a		0.0082		Major Axis a		0.011	
Minor Axis b		0.0035		Minor Axis b		0.0047	
Ellipse Rotation Angle		60		Ellipse Rotation Angle		60	
C1		C2		C3		C4	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.3379	0.3499	0.3444	0.3475	0.3516	0.3610	0.3459	0.3638
0.3396	0.3513	0.3446	0.3496	0.3498	0.3596	0.3457	0.3617
0.3444	0.3475	0.3516	0.3610	0.3459	0.3638	0.3379	0.3499
0.3446	0.3496	0.3498	0.3596	0.3457	0.3617	0.3396	0.3513
CA		CB		CC		CD	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.3376	0.3616	0.3463	0.3687	0.3452	0.3558	0.3371	0.3493
0.3371	0.3493	0.3452	0.3558	0.344	0.3428	0.3366	0.3369
0.3452	0.3558	0.3533	0.3624	0.3514	0.3487	0.3440	0.3428
0.3463	0.3687	0.3551	0.3760	0.3533	0.3624	0.3452	0.3558

## Color Bin Structure

CIE Chromaticity Diagram (Cool white),  $T_j=60^{\circ}\text{C}$ ,  $I_F=65\text{mA}$



3step(3E)				4step(4E)			
Center point		0.3818 : 0.3797		Center point		0.3818 : 0.3797	
Major Axis a		0.0094		Major Axis a		0.0125	
Minor Axis b		0.004		Minor Axis b		0.0054	
Ellipse Rotation Angle		54		Ellipse Rotation Angle		54	

E1		E2		E3		E4	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.3735	0.3746	0.3800	0.3705	0.3901	0.3849	0.3854	0.3898
0.3756	0.3759	0.3807	0.3730	0.388	0.3836	0.3847	0.3874
0.3800	0.3705	0.3901	0.3849	0.3854	0.3898	0.3735	0.3746
0.3807	0.3730	0.3880	0.3836	0.3847	0.3874	0.3756	0.3759

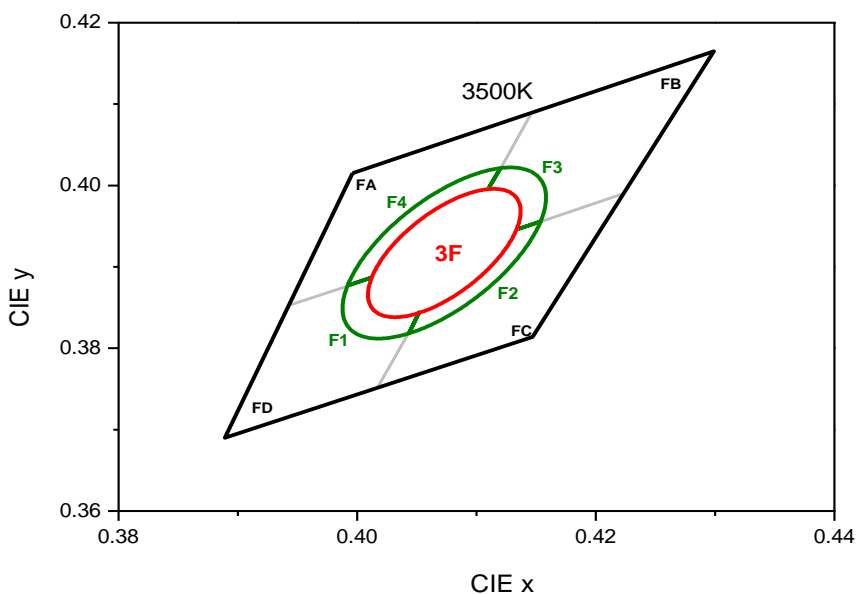
  

EA		EB		EC		ED	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.3736	0.3874	0.3871	0.3959	0.3828	0.3803	0.3703	0.3726
0.3703	0.3726	0.3828	0.3803	0.3784	0.3647	0.3670	0.3578
0.3828	0.3803	0.3952	0.3880	0.3898	0.3716	0.3784	0.3647
0.3871	0.3959	0.4006	0.4044	0.3952	0.3880	0.3828	0.3803



## Color Bin Structure

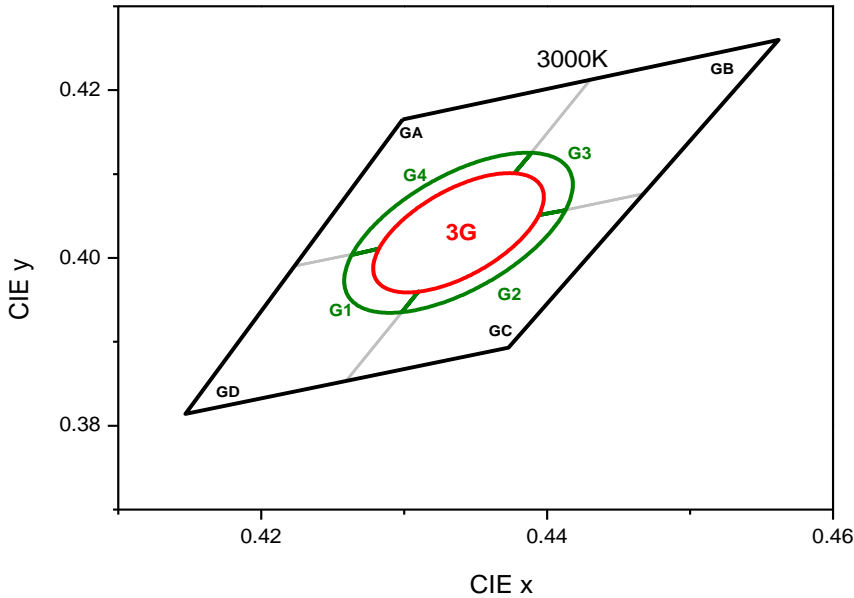
CIE Chromaticity Diagram (Cool white),  $T_j=60^{\circ}\text{C}$ ,  $I_F=65\text{mA}$



3step(3F)				4step(4F)			
Center point		0.4073 : 0.3917		Center point		0.4073 : 0.3917	
Major Axis a		0.0093		Major Axis a		0.0124	
Minor Axis b		0.0041		Minor Axis b		0.0055	
Ellipse Rotation Angle		54		Ellipse Rotation Angle		54	
F1		F2		F3		F4	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.3992	0.3877	0.4043	0.3818	0.4154	0.3956	0.4120	0.4021
0.4012	0.3887	0.4052	0.3844	0.4134	0.3946	0.4110	0.3996
0.4043	0.3818	0.4154	0.3956	0.4120	0.4021	0.3992	0.3877
0.4052	0.3844	0.4134	0.3946	0.4110	0.3996	0.4012	0.3887
FA		FB		FC		FD	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.3996	0.4015	0.4146	0.4089	0.4082	0.3920	0.3943	0.3853
0.3943	0.3853	0.4082	0.3920	0.4017	0.3751	0.3889	0.3690
0.4082	0.3920	0.4223	0.3990	0.4147	0.3814	0.4017	0.3751
0.4146	0.4089	0.4299	0.4165	0.4223	0.3990	0.4082	0.3920

## Color Bin Structure

CIE Chromaticity Diagram (Cool white),  $T_j=60^{\circ}\text{C}$ ,  $I_F=65\text{mA}$



3step(3G)				4step(4G)			
Center point		0.4338 : 0.4030		Center point		0.4338 : 0.4030	
Major Axis a		0.0083		Major Axis a		0.0112	
Minor Axis b		0.0041		Minor Axis b		0.0054	
Ellipse Rotation Angle		53		Ellipse Rotation Angle		53	

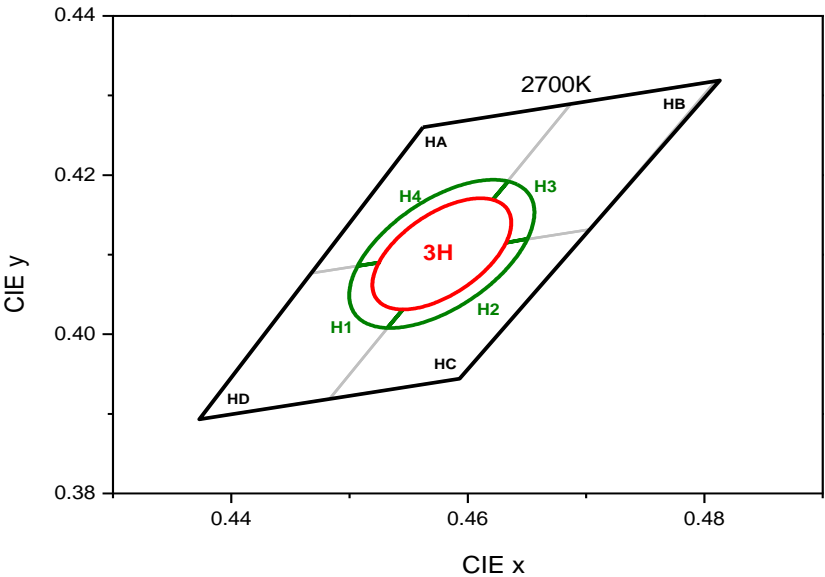
G1		G2		G3		G4	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.4264	0.4004	0.4298	0.3935	0.4413	0.4057	0.4389	0.4125
0.4282	0.4011	0.4310	0.3960	0.4394	0.4051	0.4377	0.4101
0.4298	0.3935	0.4413	0.4057	0.4389	0.4125	0.4264	0.4004
0.4310	0.3960	0.4394	0.4051	0.4377	0.4101	0.4282	0.4011

GA		GB		GC		GD	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.4299	0.4165	0.4430	0.4212	0.4345	0.4033	0.4223	0.3990
0.4223	0.399	0.4345	0.4033	0.4259	0.3853	0.4147	0.3814
0.4345	0.4033	0.4468	0.4077	0.4373	0.3893	0.4259	0.3853
0.4430	0.4212	0.4562	0.4260	0.4468	0.4077	0.4345	0.4033

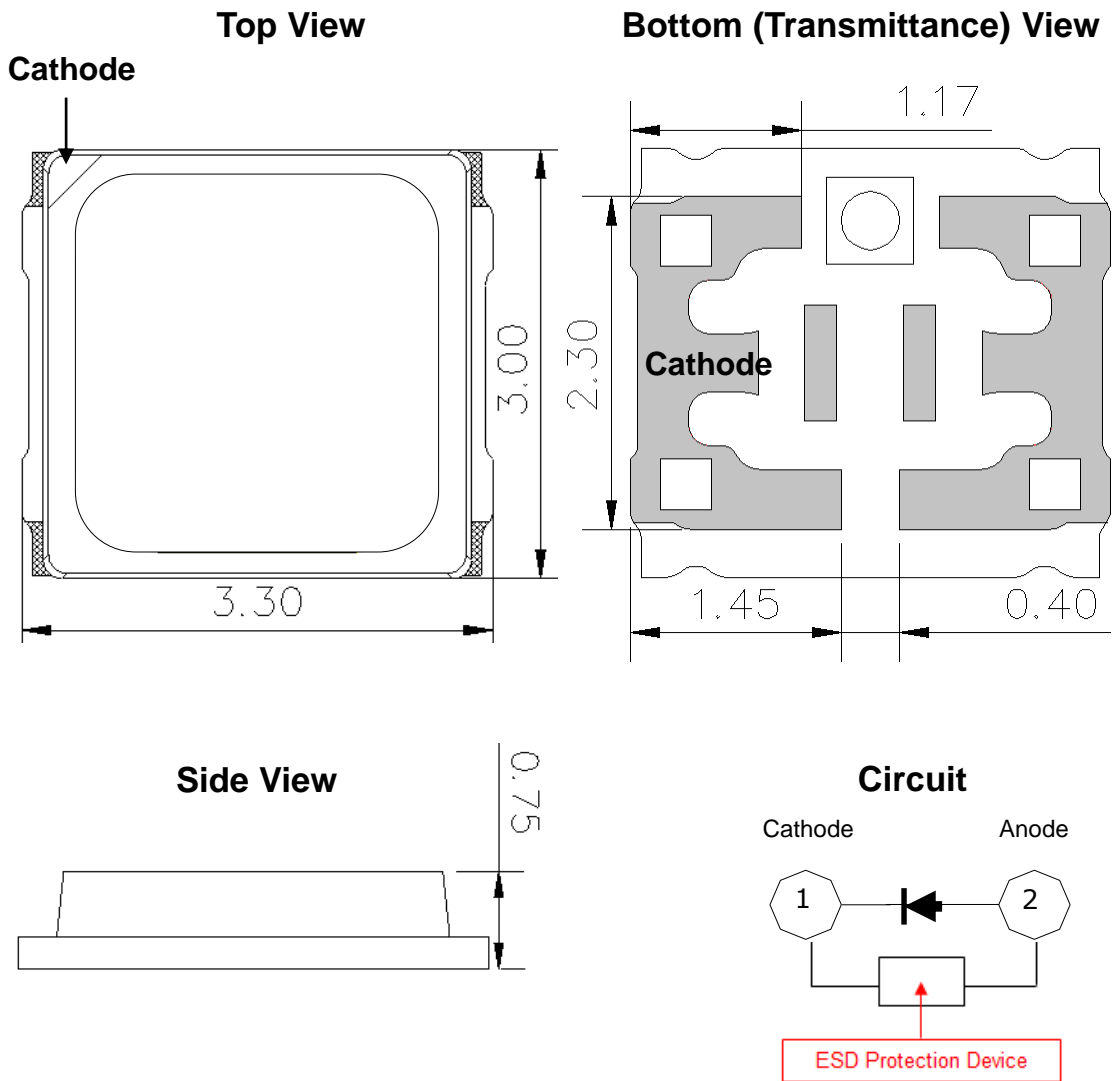
# Color Bin Structure

CIE Chromaticity Diagram (Cool white),  $T_j=60^{\circ}\text{C}$ ,  $I_F=65\text{mA}$



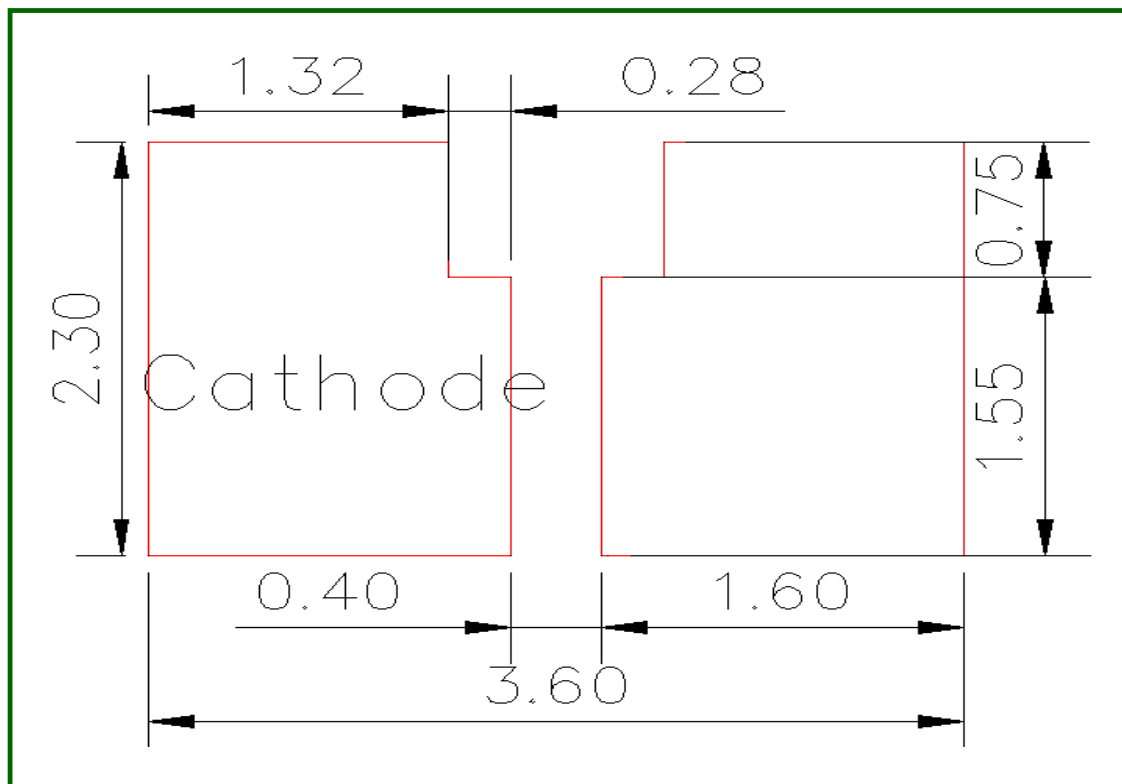
3step(3H)				4step(4H)			
Center point		0.4578 : 0.4101		Center point		0.4578 : 0.4101	
Major Axis a		0.0081		Major Axis a		0.0108	
Minor Axis b		0.0042		Minor Axis b		0.0056	
Ellipse Rotation Angle		54		Ellipse Rotation Angle		54	
H1		H2		H3		H4	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.4507	0.4086	0.4532	0.4008	0.4650	0.4120	0.4634	0.4192
0.4525	0.4090	0.4545	0.4031	0.4632	0.4115	0.4621	0.4169
0.4532	0.4008	0.4650	0.4120	0.4634	0.4192	0.4507	0.4086
0.4545	0.4031	0.4632	0.4115	0.4621	0.4169	0.4525	0.4090
HA		HB		HC		HD	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.4562	0.4260	0.4687	0.4289	0.4585	0.4104	0.4468	0.4077
0.4468	0.4077	0.4585	0.4104	0.4483	0.3919	0.4373	0.3893
0.4585	0.4104	0.4703	0.4132	0.4593	0.3944	0.4483	0.3919
0.4687	0.4289	0.4810	0.4319	0.4703	0.4132	0.4585	0.4104

## Mechanical Dimensions



- (1) All dimensions are in millimeters.
- (2) Scale : none
- (3) Undefined tolerance is  $\pm 0.07\text{mm}$

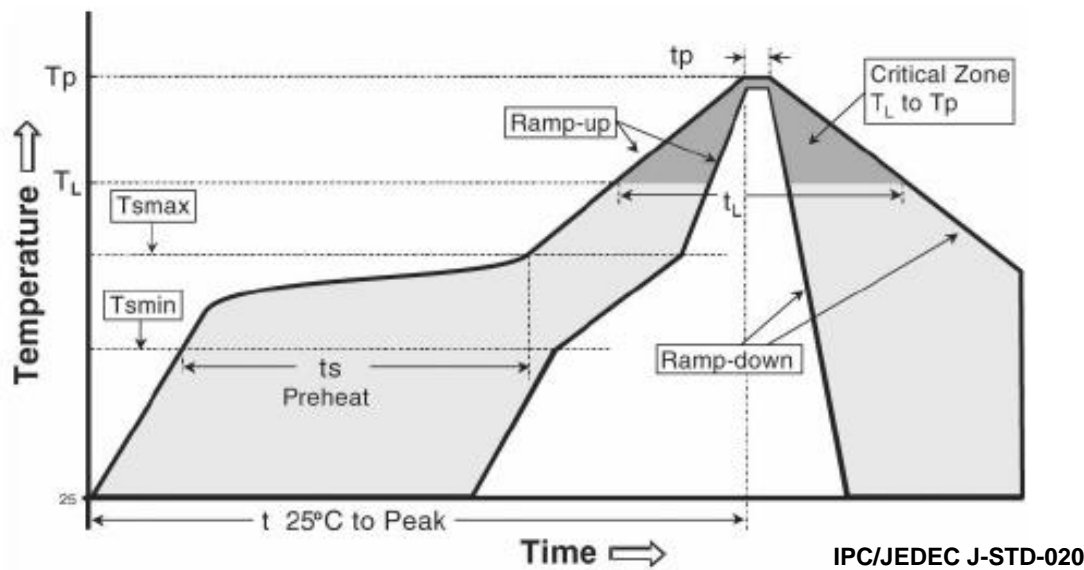
## Recommended Solder Pad



### Notes :

- (1) All dimensions are in millimeters.
- (2) Scale : none
- (3) This drawing without tolerances are for reference only
- (4) Undefined tolerance is  $\pm 0.1\text{mm}$

## Reflow Soldering Characteristics

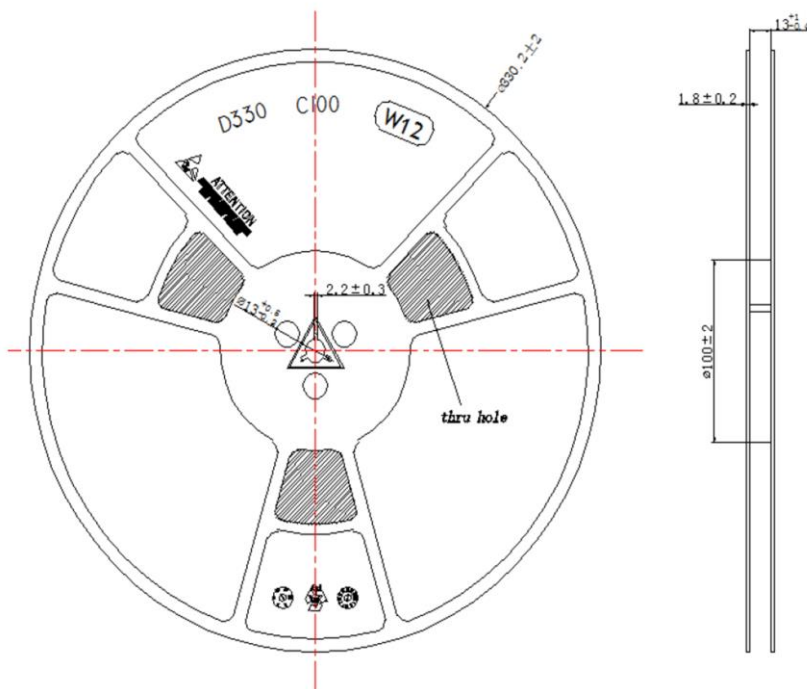
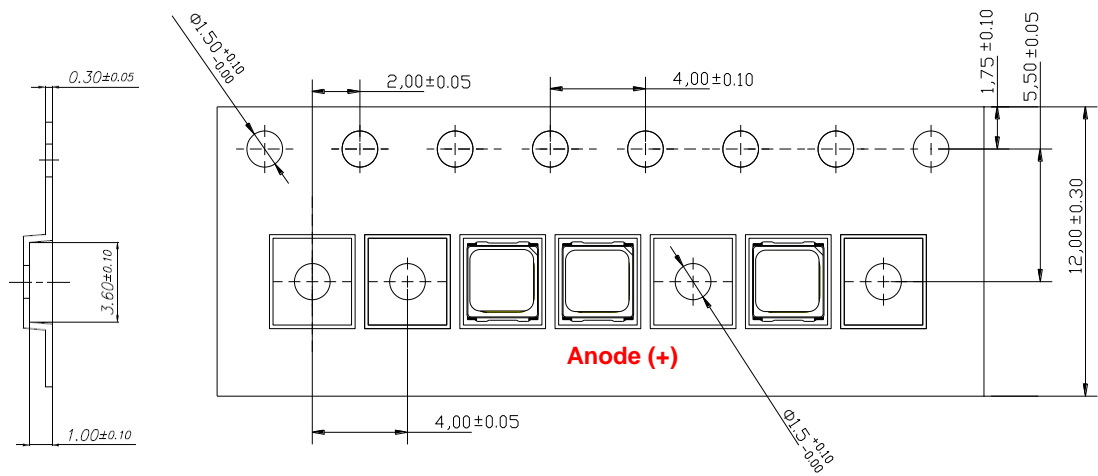


Profile Feature	Sn-Pb Eutectic Assembly	Pb-Free Assembly
Average ramp-up rate (T <sub>max</sub> to T <sub>p</sub> )	3° C/second max.	3° C/second max.
Preheat <ul style="list-style-type: none"> <li>- Temperature Min (T<sub>min</sub>)</li> <li>- Temperature Max (T<sub>max</sub>)</li> <li>- Time (T<sub>min</sub> to T<sub>max</sub>) (t<sub>s</sub>)</li> </ul>	100 °C 150 °C 60-120 seconds	150 °C 200 °C 60-180 seconds
Time maintained above: <ul style="list-style-type: none"> <li>- Temperature (T<sub>L</sub>)</li> <li>- Time (t<sub>L</sub>)</li> </ul>	183 °C 60-150 seconds	217 °C 60-150 seconds
Peak Temperature (T <sub>p</sub> )	215°C	260°C
Time within 5°C of actual Peak Temperature (tp)2	10-30 seconds	20-40 seconds
Ramp-down Rate	6 °C/second max.	6 °C/second max.
Time 25°C to Peak Temperature	6 minutes max.	8 minutes max.

### Caution

- (1) Reflow soldering is recommended not to be done more than two times. In the case of more than 24 hours passed soldering after first, LEDs will be damaged.
- (2) Repairs should not be done after the LEDs have been soldered. When repair is unavoidable, suitable tools must be used.
- (3) Die slug is to be soldered.
- (4) When soldering, do not put stress on the LEDs during heating.
- (5) After soldering, do not warp the circuit board.

## Emitter Tape & Reel Packing



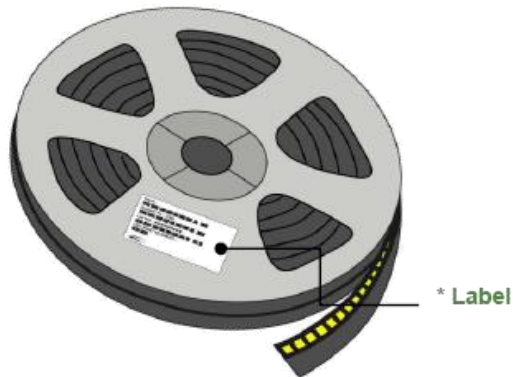
( Tolerance:  $\pm 0.2$ , Unit: mm )

### Note :

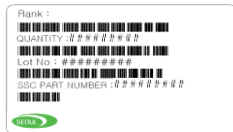
- (1) Quantity : 12,000pcs/Reel
- (2) Cumulative Tolerance : Cumulative Tolerance/10 pitches to be  $\pm 0.2$ mm
- (3) Adhesion Strength of Cover Tape  
Adhesion strength to be 0.1-0.7N when the cover tape is turned off from the carrier tape at the angle of  $10^\circ$  to the carrier tape.
- (4) Package : P/N, Manufacturing data Code No. and Quantity to be indicated on a damp proof Package.

## Emitter Tape & Reel Packing

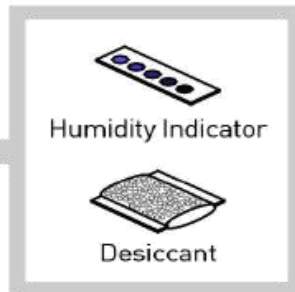
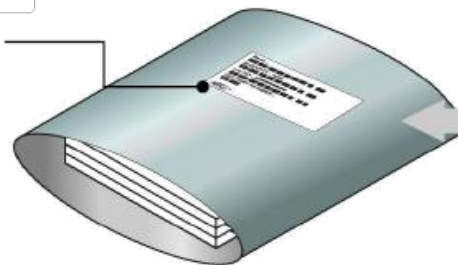
### Reel



### Aluminum Bag



\* Label



### Outer Box



\* Label



# Product Nomenclature

Table 7. Part Numbering System : X<sub>1</sub>X<sub>2</sub>X<sub>3</sub>X<sub>4</sub>X<sub>5</sub>X<sub>6</sub>X<sub>7</sub>X<sub>8</sub>-X<sub>9</sub>X<sub>10</sub>

Code	Description	Part Number	Value
X <sub>1</sub>	Company	S	
X <sub>2</sub>	Top View LED series	T	
X <sub>3</sub> X <sub>4</sub>	Color Specification	W8	CRI 80
X <sub>5</sub>	Package series	C	C series
X <sub>6</sub> X <sub>7</sub>	Characteristic code	12	
X <sub>8</sub>	Revision	E	
X <sub>9</sub> X <sub>10</sub>	Characteristic	E2	

**S 1 W 0 - 3 0 3 0 x x 8 0 0 3 - 0 0 0 0 0 0 0 0 - 0 0 0 1 3**  
X<sub>1</sub> X<sub>2</sub> X<sub>3</sub> X<sub>4</sub> X<sub>5</sub> X<sub>6</sub> X<sub>7</sub> X<sub>8</sub> X<sub>9</sub> X<sub>10</sub> X<sub>11</sub> X<sub>12</sub> X<sub>13</sub> X<sub>14</sub> X<sub>15</sub> X<sub>16</sub> X<sub>17</sub> X<sub>18</sub> X<sub>19</sub> X<sub>20</sub> X<sub>21</sub> X<sub>22</sub> X<sub>23</sub> X<sub>24</sub> X<sub>25</sub> X<sub>26</sub> X<sub>27</sub> X<sub>28</sub> X<sub>29</sub> X<sub>30</sub>

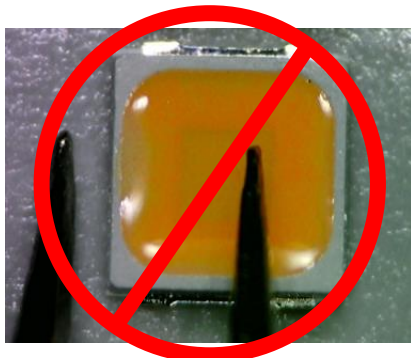
Code	Description	Order Code	Value
X <sub>1</sub>	Company	S	Seoul Semiconductor
X <sub>2</sub>	Level of Integration	1	Discrete LED
X <sub>3</sub> X <sub>4</sub>	Technology	W0	General White
X <sub>5</sub>			
X <sub>6</sub> X <sub>7</sub> X <sub>8</sub> X <sub>9</sub>	Dimension	3030	
X <sub>10</sub> X <sub>11</sub>	CCT	xx	
X <sub>12</sub> X <sub>13</sub>	CRI	80	
X <sub>14</sub> X <sub>15</sub>	Vf	03	
X <sub>16</sub>			
X <sub>17</sub> X <sub>18</sub> X <sub>19</sub>	Characteristic code Flux Rank	000	
X <sub>20</sub> X <sub>21</sub> X <sub>22</sub>	Characteristic code Vf Rank	000	
X <sub>23</sub> X <sub>24</sub>	Characteristic code Color Step	00	
X <sub>25</sub>	-		
X <sub>26</sub> X <sub>27</sub>	Type	00	
X <sub>28</sub> X <sub>29</sub> X <sub>30</sub>	Internal code	013	

Table 8. Lot Numbering System : Y<sub>1</sub>Y<sub>2</sub>Y<sub>3</sub>Y<sub>4</sub>Y<sub>5</sub>Y<sub>6</sub>Y<sub>7</sub>Y<sub>8</sub>Y<sub>9</sub>Y<sub>10</sub>-Y<sub>11</sub>Y<sub>12</sub>Y<sub>13</sub>Y<sub>14</sub>Y<sub>15</sub>Y<sub>16</sub>Y<sub>17</sub>

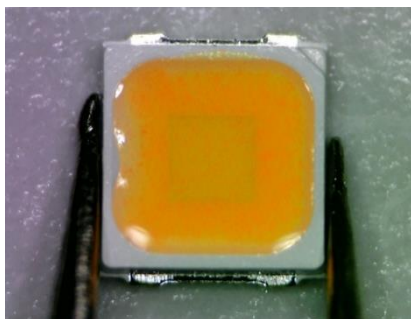
Code	Description	Lot Number	Value
Y <sub>1</sub> Y <sub>2</sub>	Year		
Y <sub>3</sub>	Month		
Y <sub>4</sub> Y <sub>5</sub>	Day		
Y <sub>6</sub>	Top View LED series		
Y <sub>7</sub> Y <sub>8</sub> Y <sub>9</sub> Y <sub>10</sub>	Mass order		
Y <sub>11</sub> Y <sub>12</sub> Y <sub>13</sub> Y <sub>14</sub> Y <sub>15</sub> Y <sub>16</sub> Y <sub>17</sub>	Internal Number		

## Handling of Silicone Resin for LEDs

(1) During processing, mechanical stress on the surface should be minimized as much as possible. Sharp objects of all types should not be used to pierce the sealing compound.



(2) In general, LEDs should only be handled from the side. By the way, this also applies to LEDs without a silicone sealant, since the surface can also become scratched.



(3) When populating boards in SMT production, there are basically no restrictions regarding the form of the pick and place nozzle, except that mechanical pressure on the surface of the resin must be prevented. This is assured by choosing a pick and place nozzle which is larger than the LED's reflector area.

(4) Silicone differs from materials conventionally used for the manufacturing of LEDs. These conditions must be considered during the handling of such devices. Compared to standard encapsulants, silicone is generally softer, and the surface is more likely to attract dust.

As mentioned previously, the increased sensitivity to dust requires special care during processing. In cases where a minimal level of dirt and dust particles cannot be guaranteed, a suitable cleaning solution must be applied to the surface after the soldering of components.

(5) SSC suggests using isopropyl alcohol for cleaning. In case other solvents are used, it must be assured that these solvents do not dissolve the package or resin.

Ultrasonic cleaning is not recommended. Ultrasonic cleaning may cause damage to the LED.

(6) Please do not mold this product into another resin (epoxy, urethane, etc) and do not handle this product with acid or sulfur material in sealed space.

## Precaution for Use

### (1) Storage

To avoid the moisture penetration, we recommend store in a dry box with a desiccant.

The recommended storage temperature range is 5°C to 30°C and a maximum humidity of RH50%.

### (2) Use Precaution after Opening the Packaging

Use proper SMT techniques when the LED is to be soldered dipped as separation of the lens may affect the light output efficiency.

Pay attention to the following:

#### a. Recommend conditions after opening the package

- Sealing

- Temperature : 5 ~ 30°C Humidity : less than RH60%

#### b. If the package has been opened more than 4 week(MSL\_2a) or the color of the desiccant changes, components should be dried for 10-24hr at 65±5°C

### (3) Do not apply mechanical force or excess vibration during the cooling process to normal temperature after soldering.

### (4) Do not rapidly cool device after soldering.

### (5) Components should not be mounted on warped (non coplanar) portion of PCB.

### (6) Radioactive exposure is not considered for the products listed here in.

### (7) Gallium arsenide is used in some of the products listed in this publication.

These products are dangerous if they are burned or shredded in the process of disposal.

It is also dangerous to drink the liquid or inhale the gas generated by such products when chemically disposed of.

### (8) This device should not be used in any type of fluid such as water, oil, organic solvent and etc.

When washing is required, IPA (Isopropyl Alcohol) should be used.

### (9) When the LEDs are in operation the maximum current should be decided after measuring the package temperature.

## Precaution for Use

- (10) The appearance and specifications of the product may be modified for improvement without notice.
- (11) Long time exposure of sunlight or occasional UV exposure will cause lens discoloration.
- (12) VOCs (Volatile organic compounds) emitted from materials used in the construction of fixtures can penetrate silicone encapsulants of LEDs and discolor when exposed to heat and photonic energy. The result can be a significant loss of light output from the fixture. Knowledge of the properties of the materials selected to be used in the construction of fixtures can help prevent these issues.
- (13) Attaching LEDs, do not use adhesives that outgas organic vapor.
- (14) The driving circuit must be designed to allow forward voltage only when it is ON or OFF.  
If the reverse voltage is applied to LED, migration can be generated resulting in LED damage.
- (15) Similar to most Solid state devices;  
LEDs are sensitive to Electro-Static Discharge (ESD) and Electrical Over Stress (EOS).  
Below is a list of suggestions that Seoul Semiconductor purposes to minimize these effects.

### a. ESD (Electro Static Discharge)

Electrostatic discharge (ESD) is defined as the release of static electricity when two objects come into contact. While most ESD events are considered harmless, it can be an expensive problem in many industrial environments during production and storage. The damage from ESD to LEDs may cause the product to demonstrate unusual characteristics such as:

- Increase in reverse leakage current lowered turn-on voltage
- Abnormal emissions from the LED at low current

The following recommendations are suggested to help minimize the potential for an ESD event.  
One or more recommended work area suggestions:

- Ionizing fan setup
- ESD table/shelf mat made of conductive materials
- ESD safe storage containers

One or more personnel suggestion options:

- Antistatic wrist-strap
- Antistatic material shoes
- Antistatic clothes

Environmental controls:

- Humidity control (ESD gets worse in a dry environment)

## Precaution for Use

### b. EOS (Electrical Over Stress)

Electrical Over-Stress (EOS) is defined as damage that may occur when an electronic device is subjected to a current or voltage that is beyond the maximum specification limits of the device.

The effects from an EOS event can be noticed through product performance like:

- Changes to the performance of the LED package  
(If the damage is around the bond pad area and since the package is completely encapsulated the package may turn on but flicker show severe performance degradation.)
- Changes to the light output of the luminaire from component failure
- Components on the board not operating at determined drive power

Failure of performance from entire fixture due to changes in circuit voltage and current across total circuit causing trickle down failures. It is impossible to predict the failure mode of every LED exposed to electrical overstress as the failure modes have been investigated to vary, but there are some common signs that will indicate an EOS event has occurred:

- Damaged may be noticed to the bond wires (appearing similar to a blown fuse)
- Damage to the bond pads located on the emission surface of the LED package  
(shadowing can be noticed around the bond pads while viewing through a microscope)
- Anomalies noticed in the encapsulation and phosphor around the bond wires.
- This damage usually appears due to the thermal stress produced during the EOS event.

### c. To help minimize the damage from an EOS event Seoul Semiconductor recommends utilizing:

- A surge protection circuit
- An appropriately rated over voltage protection device
- A current limiting device

## Company Information

### **Published by**

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### **Company Information**

Seoul Semiconductor ([www.SeoulSemicon.com](http://www.SeoulSemicon.com)) manufactures and packages a wide selection of light emitting diodes (LEDs) for the automotive, general illumination/lighting, Home appliance, signage and back lighting markets. The company is the world's fifth largest LED supplier, holding more than 10,000 patents globally, while offering a wide range of LED technology and production capacity in areas such as "nPola", "Acrich", the world's first commercially produced AC LED, and "Acrich MJT - Multi-Junction Technology" a proprietary family of high-voltage LEDs.

The company's broad product portfolio includes a wide array of package and device choices such as Acrich and Acirch2, high-brightness LEDs, mid-power LEDs, side-view LEDs, and through-hole type LEDs as well as custom modules, displays, and sensors.

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